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Jameco Part Number 832683

June 1998



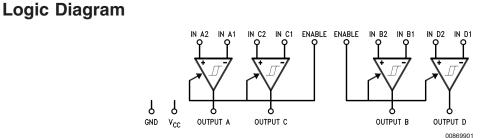
DS34C86T Quad CMOS Differential Line Receiver General Description Features

The DS34C86T is a quad differential line receiver designed to meet the RS-422, RS-423, and Federal Standards 1020 and 1030 for balanced and unbalanced digital data transmission, while retaining the low power characteristics of CMOS.

The DS34C86T has an input sensitivity of 200 mV over the common mode input voltage range of ±7V. Hysteresis is provided to improve noise margin and discourage output instability for slowly changing input waveforms.

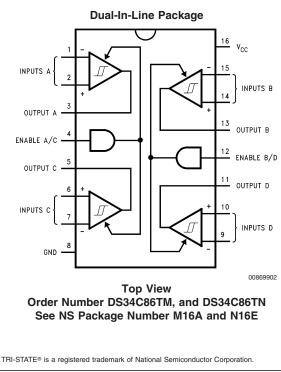
The DS34C86T features internal pull-up and pull-down resistors which prevent output oscillation on unused channels. Separate enable pins allow independent control of receiver pairs. The TRI-STATE® outputs have 6 mA source and sink capability. The DS34C86T is pin compatible with the

- CMOS design for low power
- ±0.2V sensitivity over the input common mode voltage range
- Typical propagation delays: 19 ns
- Typical input hysteresis: 60 mV
- Inputs won't load line when V_{CC} = 0V
- Meets the requirements of EIA standard RS-422
- TRI-STATE outputs for system bus compatibility
- Available in surface mount
- Open input Failsafe feature, output high for open input



Connection Diagram

DS3486.



Truth Table

Enable	Input	Output
L	Х	Z
Н	$V_{ID} \ge V_{TH}$ (Max)	Н
Н	$V_{ID} \le V_{TH}$ (Min)	L
Н	Open*	Н

*Open, not terminated Z = TRI-STATE

Absolute Maximum Ratings (Notes 1,

2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V_{CC})	7V
Input Common Mode Range (V	
см)	±14V
Differential Input Voltage (V	
DIFF)	±14V
Enable Input Voltage (V IN)	7V
Storage Temperature Range (T	–65°C to
sтg)	+150°C
Lead Temperature (Soldering 4	
sec)	260°C

Maximum Power Dissipation at 25°C (Note 5)Plastic "N" Package1645 mWSOIC Package1190 mWCurrent Per Output±25 mA

This device does not meet 2000V ESD rating. (Note 4)

Operating Conditions

	Min	Мах	Unit
Supply Voltage (V _{CC})	4.50	5.50	V
Operating Temperature Range (T _A)	-40	+85	°C
Enable Input Rise or Fall Times		500	ns

DC Electrical Characteristics (Note 3)

 $V_{CC} = 5V \pm 10\%$ (unless otherwise specified)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{TH}	Minimum Differential	$V_{OUT} = V_{OH} \text{ or } V_{OL}$	-200	35	+200	mV
	Input Voltage	$-7V < V_{CM} < +7V$				
R _{IN}	Input Resistance	$V_{\rm IN} = -7V, +7V$	5.0	6.8	10	kΩ
		(Other Input = GND)				
I _{IN}	Input Current	V _{IN} = +10V, Other Input = GND		+1.1	+1.5	mA
	(Under Test)	$V_{IN} = -10V$, Other Input = GND		-2.0	-2.5	mA
V _{OH}	Minimum High Level	$V_{CC} = Min., V_{(DIFF)} = +1V$	3.8	4.2		V
	Output Voltage	$I_{OUT} = -6.0 \text{ mA}$				
V _{OL}	Maximum Low Level	$V_{CC} = Max., V_{(DIFF)} = -1V$		0.2	0.3	V
	Output Voltage	I _{OUT} = 6.0 mA				
V _{IH}	Minimum Enable High		2.0			V
	Input Level Voltage					
V _{IL}	Maximum Enable Low				0.8	V
	Input Level Voltage					
l _{oz}	Maximum TRI-STATE	$V_{OUT} = V_{CC}$ or GND,				
	Output Leakage Current	TRI-STATE Control = V _{IL}		±0.5	±5.0	μA
I _I	Maximum Enable Input	V _{IN} = V _{CC} or GND			±1.0	μA
	Current					
I _{cc}	Quiescent Power	$V_{CC} = Max., V_{(DIFF)} = +1V$		16	23	mA
	Supply Current					
V _{HYST}	Input Hysteresis	$V_{CM} = 0V$		60		mV

AC Electrical Characteristics (Note 3)

Symbol	Parameter	Conditions	Min	Тур	Мах	Units
t _{PLH} ,	Propagation Delay	$C_L = 50 \text{ pF}$				
t _{PHL}	Input to Output	$V_{DIFF} = 2.5V$		19	30	ns
		$V_{CM} = 0V$				
t _{RISE} ,	Output Rise and	C _L = 50 pF				
t _{FALL}	Fall Times	$V_{DIFF} = 2.5V$		4	9	ns
		$V_{CM} = 0V$				
t _{PLZ} ,	Propagation Delay	C _L = 50 pF				
t _{PHZ}	ENABLE to Output	$R_{L} = 1000\Omega$		13	18	ns

 $V_{CC} = 5V \pm 10\%$ (unless otherwise specified) (Figures 1, 2, 3)

AC Electrical Characteristics (Note 3) (Continued) $V_{CC} = 5V \pm 10\%$ (unless otherwise specified) (*Figures 1, 2, 3*)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
		$V_{DIFF} = 2.5V$				
t _{PZL} ,	Propagation Delay	C _L = 50 pF				
t _{PZH}	ENABLE to Output	$R_L = 1000\Omega$		13	21	ns
		$V_{DIFF} = 2.5V$				

Note 1: Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Unless otherwise specified, all voltages are referenced to ground.

Note 3: Unless otherwise specified, Min/Max limits apply across the operating temperature range.

All typicals are given for V_{CC} = 5V and T_A = 25 $^\circ C.$

Note 4: ESD Rating; HBM (1.5kΩ, 100 pF)

Inputs \geq 2000V

All other pins \geq 1000V

EIAJ (0 Ω , 200 pF) \ge 350V

Note 5: Ratings apply to ambient temperature at 25°C. Above this temperature derate N Package 13.16 mW/°C, and M Package 9.52 mW/°C.

Comparison Table of Switching Characteristics into "LS-Type" Load (Note 6) $V_{CC} = 5V$, $T_A = 25^{\circ}C$ (*Figures 4, 5*)

Symbol	Parameter	DS34C86		DS3486		Units
		Тур	Max	Тур	Мах	
t _{PHL(D)}	Propagation Delay Time	17		19		ns
	Output High to Low					
t _{PLH(D)}	Propagation Delay Time	19		19		ns
	Output Low to High					
t _{PLZ}	Output Low to TRI-STATE	13		23		ns
t _{PHZ}	Output High to TRI-STATE	12		25		ns
t _{PZH}	Output TRI-STATE to High	13		18		ns
t _{PZL}	Output TRI-STATE to Low	13		20		ns

Note 6: This Table is provided for comparison purposes only. The values in this table for the DS34C86 reflect the performance of the device but are not tested or guaranteed.

Test and Switching Waveforms

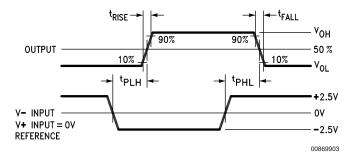
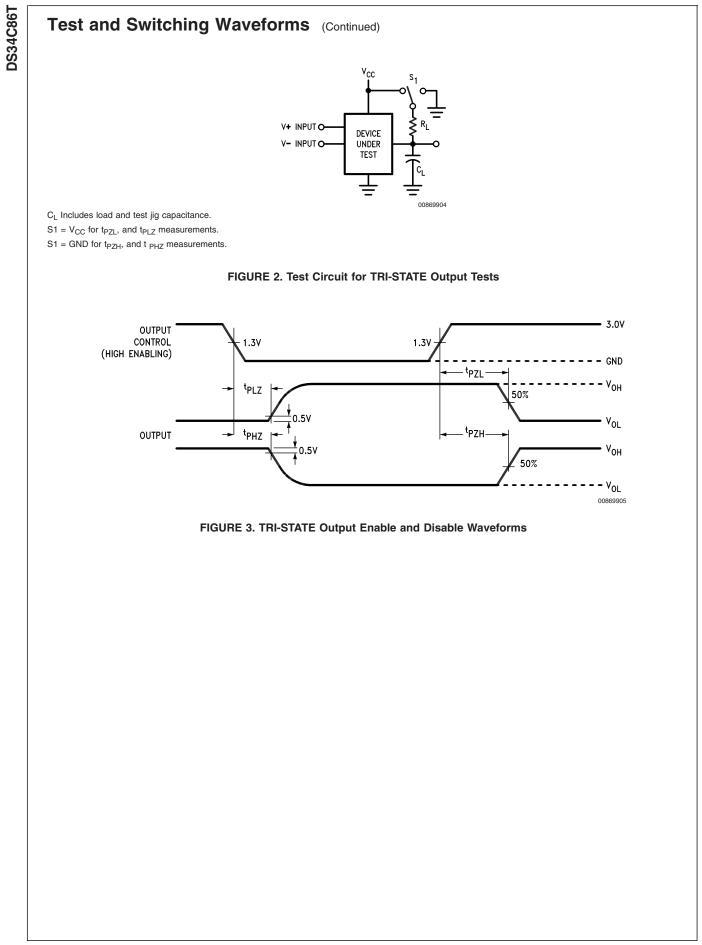
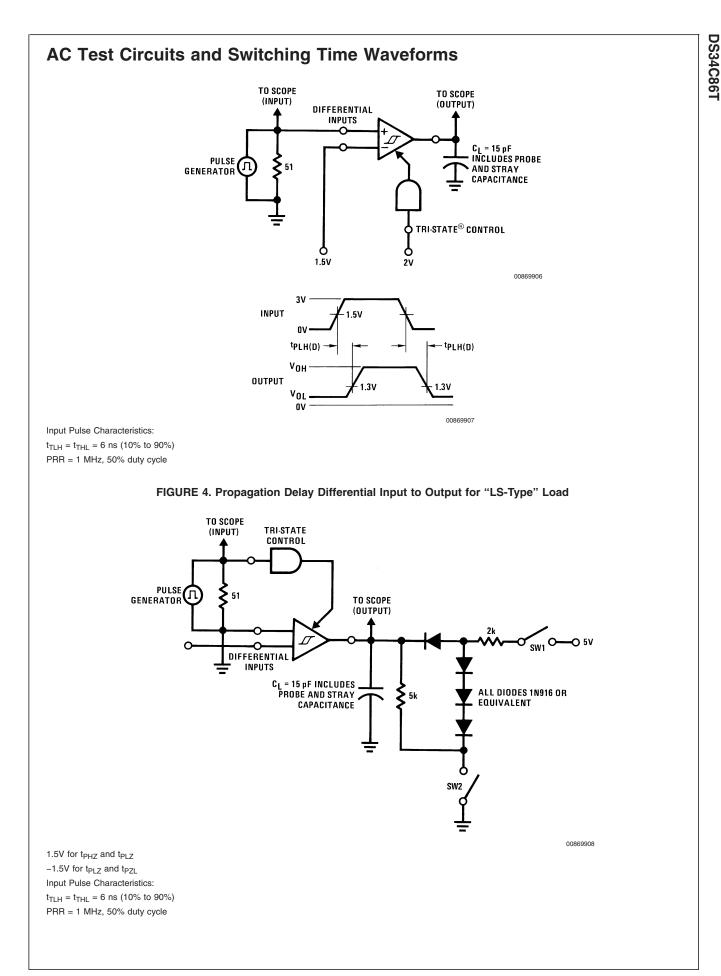


FIGURE 1. Propagation Delays





AC Test Circuits and Switching Time Waveforms (Continued)

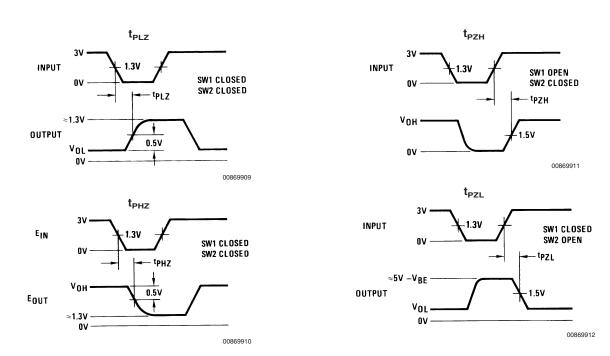
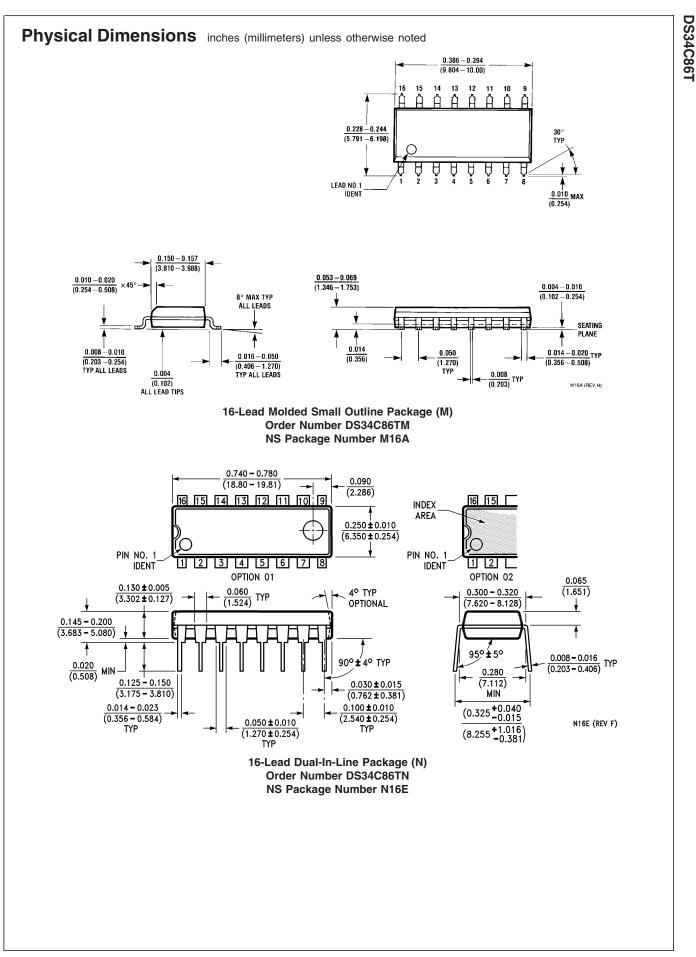


FIGURE 5. Propagation Delay TRI-STATE Control Unit to Output for "LS-Type" Load



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Notes